



N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	RDS(ON) MAX	I _{D MAX} T _C = +25°С
700V	1.4Ω @ V _{GS} = 10V	4.7A

Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

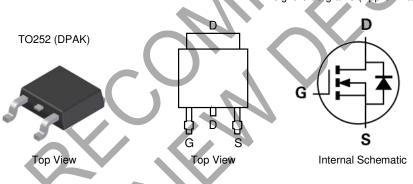
- Adaptors
- LCDs & PDP TVs
- Lighting

Features

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low Gate Input Resistance
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
- Solderable per MIL-STD-202, Method 208 🙆
 - Weight: 0.33 grams (Approximate)



Ordering Information (Note 4)

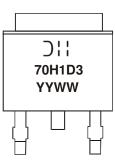
Part Number	Backaga	Packing		
Part Nulliber	Package	Qty.	Carrier	
DMJ70H1D3SK3-13	TO252 (DPAK)	2,500	Tape & Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



 \bigcirc **! !** = Manufacturer's Marking 70H1D3 = Product Type Marking Code YYWW = Date Code Marking YY or <u>YY</u> = Last Two Digits of Year (ex: 22 = 2022) WW or <u>WW</u> = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	700	V	
Gate-Source Voltage		Vgss	±30	V
Continuous Drain Current (Notes 5 & 9) V_{GS} = 10V	T _C = +25°C T _C = +100°C	ID	4.7 3.0	А
Maximum Body Diode Forward Current (Note 6)		ls	2	А
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)		lsм	5	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	IDM	5	А	
Avalanche Current, L = 60mH		las	1	А
Avalanche Energy, L = 60mH		Eas	29	mJ
Peak Diode Recovery dv/dt (Note 7)		dv/dt	4	V/ns

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_{\rm C} = +25^{\circ}{\rm C}$ $T_{\rm C} = +100^{\circ}{\rm C}$	PD	57 23	W
Thermal Resistance, Junction to Ambient (Note 6)		Reja	80	°C M/
Thermal Resistance, Junction to Case (Note 5)		Rejc	2.2	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

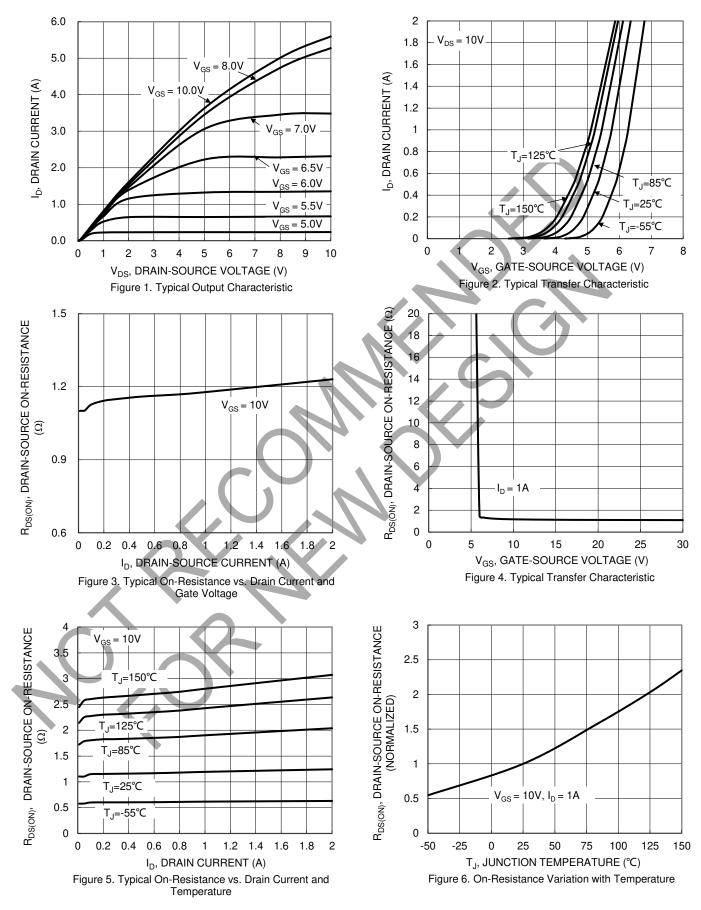
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BVDSS	700	—	_	V	$V_{GS} = 0V$, $I_D = 250\mu A$
Zero Gate Voltage Drain Current	IDSS		-	1	μA	$V_{DS} = 700V, V_{GS} = 0V$
Gate-Source Leakage	lgss			100	nA	$V_{GS} = \pm 30V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	VGS(TH)	2	_	5	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance	RDS(ON)	-	1.26	1.4	Ω	V _{GS} = 10V, I _D = 1A
Diode Forward Voltage	V _{SD}	—	_	1.3	V	$V_{GS} = 0V, I_S = 5A$
DYNAMIC CHARACTERISTICS (Note 7)						-
Input Capacitance	Ciss	—	264	_		V _{DS} = 100V, f = 1MHz, V _{GS} = 0V
Output Capacitance	Coss	—	18	_	pF	
Reverse Transfer Capacitance	Crss	_	2.8	_		
Gate Resistance	Rg		4.7	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Qg		9.8	_		$V_{DD} = 480V, I_D = 1.5A,$ $V_{GS} = 10V$
Gate-Source Charge	Qgs	_	1.7	_	nC	
Gate-Drain Charge	Q _{gd}		6	_		
Turn-On Delay Time	td(on)		9	_		
Turn-On Rise Time	tR	—	11	_	20	$\label{eq:VDD} \begin{split} V_{DD} &= 400V, \ V_{GS} = 13V, \\ R_g &= 10.2\Omega, \ I_D = 1.5A \end{split}$
Turn-Off Delay Time	td(OFF)		31		ns	
Turn-Off Fall Time	tF		19	_		
Body Diode Reverse Recovery Time	trr		145	_	ns	
Body Diode Reverse Recovery Charge	Qrr		0.8		μC	−Is =1.5A, di/dt = 100A/µs

Notes: 5. Device mounted on an infinite heatsink.

bevice mounted on FR-4 substrate PC board, 2oz. copper, with minimum recommended pad layout.
Guaranteed by design. Not subject to production testing.
Short duration pulse test used to minimize self-heating effect.
Drain current limited by maximum junction temperature.



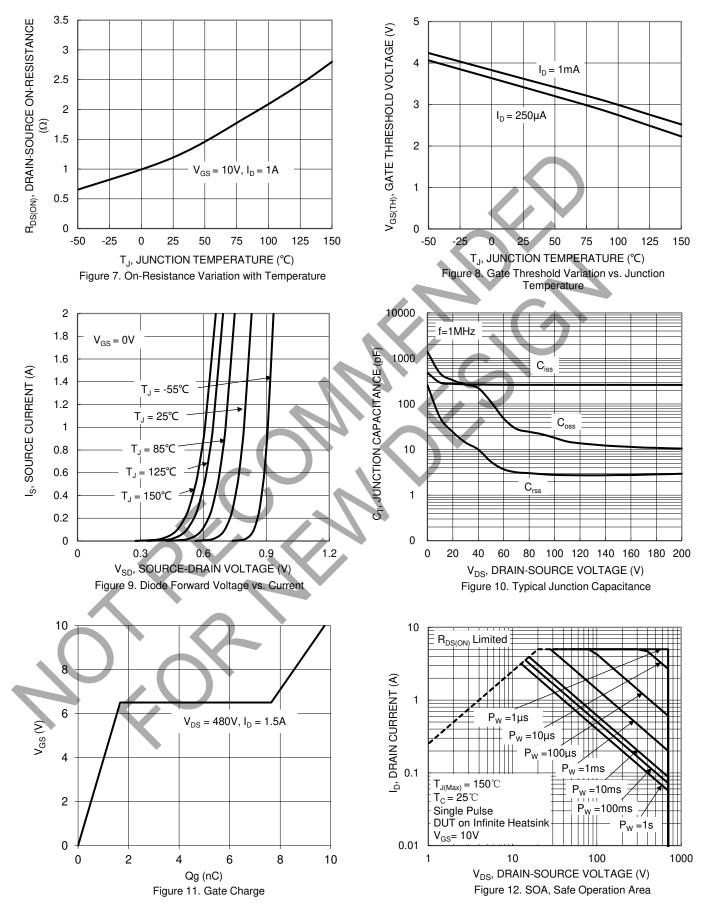
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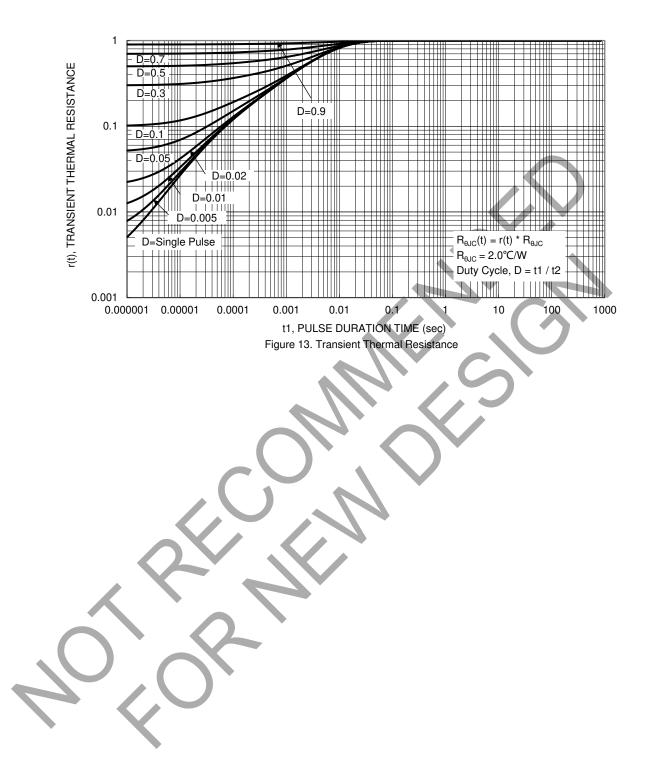
DMJ70H1D3SK3 Document number: DS40475 Rev. 3 - 3



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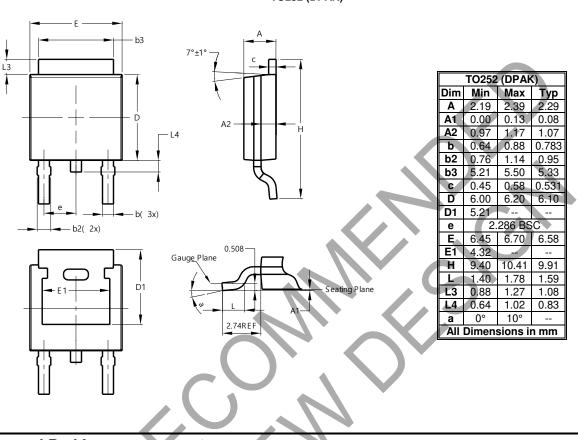






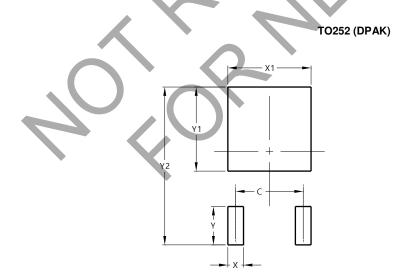
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

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Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700



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